ALPHANUMERIC INDEX — CROSS-REFERENCE

The following table represents an index and cross-reference guide for all low-frequency power transistors which are either manufactured directly by Motorola or for which Motorola manufactures a suitable equivalent. Where the Motorola part number differs from the industry part number, the Motorola device is a "form, fit and function" replacement for the industry type number — however, subtle differences in characteristics and/or specifications may exist.

1

Industry Part Number	Motorola Direct Replacement	Motorola Similar Replacement	Page Number
1SI10A-100		MJ16018	3-782
2N1487		2N5877	3-120
2N1488		2N5878	3-120
2N1489		2N5877	3-120
2N1490		2N5878	3-120
2N1702		2N5877	3-120
2N3016		2N5337	3-97
2N3021		2N3789	3-56
2N3022		2N3789	3-56
2N3023		2N3789	3-56
2N3024		2N3791	3-56
2N3025		2N3791	3-56
2N3026		2N3791	3-56
2N3054	2N3054		3-2
2N3054A	2N3054A		3-2
2N3055	2N3055		3-6
2N3055A	2N3055A		3-9
2N3055H		2N3055A	3-9
2N3055JAN		2N5302JAN	3-93
2N3055SD		2N3055A	3-9
2N3055UB		2N3055A	3-9
2N3076		2N6249	3-164
2N3079		2N6308	3-181
2N3080		2N6543	3-215
2N3171		2N3789	3-56
2N3172		2N3789	3-56
2N3173		2N3790	3-56
2N3174		MJ15016	3-9
2N3183		2N3789	3-56
2N3184		2N3789	3-56
2N3185		2N3790	3-56
2N3186		MJ15016	3-9
2N3195		2N3789	3-56
2N3196		2N3790	3-56
2N3198		MJ15016	3-9
2N3202		2N3719	3-32
2N3203		2N3720	3-32
2N3204		2N6303	3-32
2N3232		2N5877	3-120
2N3233		2N5882	3-123
2N3234		2N5760	3-116
2N3235		2N3055	3-6
2N3236		2N5882	3-123
2N3237		2N5302	3-93
2N3238		2N5882	3-123
2N3239		2N5882	3-123
2N3240		2N5882	3-123
2N3419		2N5336	3-97
2N3420		2N5336	3-97
2N3421		2N5336	3-97

Industry Part Number	Motorola Direct Replacement	Motorola Similar Replacement	Page Number
2N3441	2N3441		3-13
2N3442	2N3442		3-15
2N3445	2N3447		3-18
2N3446	2N3448		3-18
2N3447	2N3447		3-18
2N3448	2N3448		3-18
2N3583	2N3583		3-20
2N3584	2N3584		3-20
2N3585	2N3585		3-20
2N3667		2N5881	3-123
2N3713		2N5881	3-123
2N3714	2N3714		3-26
2N3715	2N3715		3-26
2N3715JAN	2N3715JAN		3-26
2N3715JTX	2N3715JTX		3-26
2N3715JTXV	2N3715JTXV		3-26
2N3716	2N3716		3-26
2N3716JAN	2N3716JAN		3-26
2N3716JTX	2N3716JTX		3-26
2N3716JTXV	2N3716JTXV		3-26
2N3719	2N3719		3-32
2N3720	2N3720		3-32
2N3738	2N3738		3-37
2N3739	2N3739		3-37
2N3739JAN	2N3739JAN		3-37
2N3739JTX	2N3739JTX		3-37
2N3739JTXV	2N3739JTXV		3-37
2N3740	2N3740		3-41
2N3740A		2N3740	3-41
2N3740JAN	2N3740JAN		3-41
2N3740JTX	2N3740JTX		3-41
2N3740JTXV	2N3740JTXV		3-41
2N3741	2N3741		3-41
2N3741A	2N3741A		3-41
2N3741JAN	2N3741JAN		3-41
2N3741JTX	2N3741JTX		3-41
2N3741JTXV	2N3741JTXV		3-41
2N3766	2N3766		3-44
2N3766JAN	2N3766JAN		3-44
2N3766JTX	2N3766JTX		3-44
2N3766JTXV	2N3766JTXV		3-44
2N3767	2N3767		3-44
2N3767JAN	2N3767JAN		3-44
2N3767JTX	2N3767JTX		3-44
2N3767JTXV	2N3767JTXV		3-44
2N3771	2N3771		3-48
2N3772	2N3772		3-48
2N3773	2N3773		3-52
2N3788		2N6543	3-215
2N3789	2N3789		3-56

TABLE 13 — POWER SWITCHING TRANSISTORS (continued)

I_C Cont Amps Max	$V_{CEO(sus)}$ Volts Min	Device Type NPN	Device Type PNP	h_{FE} Min/Max	@ I_C Amp	Resistive Switching t_s μs Max	Resistive Switching t_f μs Max	Resistive Switching @ I_C Amp	f_T MHz Min	P_D (Case) Watts @ 25°C	Case JEDEC/MOT
4	30	BD185		15 min	2				20	40	TO-225AA/77
	45	BD785	BD786	20 min	2				50	15	TO-225AA/77
	60	2N4877		20/100	4	1.5	0.5	4	30	10	TO-205AD/79
		BD189		15 min	2				20	40	TO-225AA/77
		BD787	BD788	20 min	2				50	15	TO-225AA/77
	80	BD789	BD790	10 min	2				40	15	TO-225AA/77
	100	BD791	BD792	10 min	2				40	15	TO-225AA/77
5	80	2N5337	2N6191	60/240	2	2	0.2	2	30	10	TO-205AD/79
	100	2N5339	2N6193	60/240	2	2	0.2	2	30	10	TO-205AD/79
7	60	2N6315	2N6317	20/100	2.5	1	0.8	2.5	4	90	TO-213AA/80
	80	2N5428		60/240	2	2	0.2	2	30	60	TO-213AA/80
		2N6316	2N6318	20/100	2.5	1	0.8	2.5	4	90	TO-213AA/80
	100	2N5430		60/240	2	2	0.2	2	30	60	TO-213AA/80
7.5	60	2N3447		40/120	5	2	0.35	5	10	115	TO-204/1
	80	2N3448		40/120	5	2	0.35	5	10	115	TO-204/1
8	120	MJE15028	MJE15029	20 min	4	0.4 typ	0.18 typ	5	30	50	TO-220/221A
	150	MJE15030	MJE15031	20 min	4	0.4 typ	0.18 typ	5	30	50	TO-220/221A
10	60	2N5877	2N5875	20/100	4	1	0.8	4	4	150	TO-204/1
	80	2N5878	2N5876	20/100	4	1	0.8	4	4	150	TO-204/1
15	60	2N5881	2N5879	20/100	6	1	0.8	6	4	160	TO-204/1
	80	2N5882	2N5880	20/100	6	1	0.8	6	4	160	TO-204/1
18	160	BUX41N		8 min	12	1.2	0.25	12	8	120	TO-204/1
20	75	2N5039		20/100	10	1.5	0.5	10	60	140	TO-204/1
	80	2N5303	2N5745	15/60	10	2	1	10	2	200	TO-204/1
	90	2N5038		20/100	12	1.5	0.5	12	60	140	TO-204/1
	125	BUX40		8 min	15	1	0.25	15	8	120	TO-204/1
	160	BUV11N		10 min	15	1.2	0.25	15	8	150	TO-204/1
25	60	2N5885	2N5883	20/100	10	1	0.8	10	4	200	TO-204/1
	80	2N5886	2N5884	20/100	10	1	0.8	10	4	200	TO-204/1
			2N6436	30/120	10	1	0.25	10	40	200	TO-204/1
	100	2N6338	2N6437	30/120	10	1	0.25	10	40	200	TO-204/1
	120	2N6339	2N6438	30/120	10	1	0.25	10	40	200	TO-204/1
	125	BUV10		10 min	20	1.2	0.25	20	8	150	TO-204/1
		BUV10N		10 min	20	1.55	0.45	15	10	175	TO-204/1
	140	2N6340		30/120	10	1	0.25	10	40	200	TO-204/1
	150	2N6341		30/120	10	1	0.25	10	40	200	TO-204/1
30	40	2N5301	2N4398	15/60	15	2	1	10	2	200	TO-204/1
	60	2N5302	2N4399	15/60	15	2	1	10	2	200	TO-204/1
	90	BUX39		8 min	20	1	0.25	20	8	120	TO-204/1

(continued)

2N3447
2N3448

HIGH-SPEED SILICON ANNULAR NPN POWER TRANSISTORS

. . . for switching and amplifier applications

FEATURES

- Fast Switching: Total Switching Time = 1.2 μs (Typ) @ 5.0 A
- High Gain: h_{FE} = 40 to 120 @ 5.0 Amps
- Guaranteed DC Safe Area: 1.5 Amps (Min) @ V_{CE} = 40 Vdc
- Low $V_{CE(sat)}$: 1.0 Volt (Typ), 1.5 Volts (Max) @ 5.0 Amps
- Excellent Beta Linearity

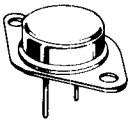
APPLICATIONS

- Specified safe area of this series allows reliable design for inverters, converters, hammer, and servo drivers.
- Fast response makes it ideal for series regulators; high switching speeds enhance its use in switching regulators.
- Wide bandwidth and flat beta hold-up result in exceptional amplifier characteristics.

7.5 AMPERE

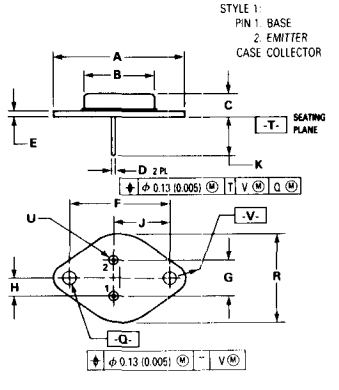
POWER TRANSISTORS SILICON NPN

60-80 VOLTS
115 WATTS



MAXIMUM RATING

Rating	Symbol	2N3447	2N3448	Unit
Collector-Emitter Voltage	V_{CEO}	60	80	Vdc
Collector-Base Voltage	V_{CB}	80	100	Vdc
Emitter-Base Voltage	V_{EB}	6.0	10	Vdc
Collector Current-Continuous	I_C	7.5		Adc
Base Current - Continuous	I_B	4.0		Adc
Total Device Dissipation	P_D	Figure 1, 2	Figure 1, 3	Watts
Operating Junction Temperature Range	T_J	−65 to +200		°C

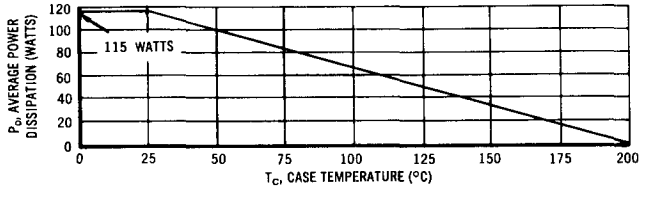


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	MILLIMETERS MIN	MILLIMETERS MAX	INCHES MIN	INCHES MAX
A	—	39.37	—	1.550
B	—	21.08	—	0.830
C	6.35	8.25	0.250	0.325
D	0.97	1.09	0.038	0.043
E	1.40	1.77	0.055	0.070
F	30.15 BSC		1.187 BSC	
G	10.92 BSC		0.430 BSC	
H	5.46 BSC		0.215 BSC	
J	16.89 BSC		0.665 BSC	
K	11.18	12.19	0.440	0.480
Q	3.84	4.19	0.151	0.165
R	—	26.67	—	1.050
U	4.83	5.33	0.190	0.210
V	3.84	4.19	0.151	0.165

CASE 1-06
TO-204AA
(TO-3)

FIGURE 1 – POWER DERATING CURVE



These transistors are also subject to safe area curves as indicated by Figures 2, 3. Both limits are applicable and must be observed.

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